



Att. Docket No. 10191/1629

**THE UNITED STATES PATENT AND TRADEMARK OFFICE**

Appl. Serial No. : 09/720,761 Confirmation No. 5642  
Title : METHOD OF PLASMA  
ETCHING OF SILICON  
Applicant(s) : Franz LAERMER et al.  
Filed : March 26, 2001  
TC/A.U. : 1765  
Examiner : Kin Chan Chen  
Docket No. : 10191/1629  
Customer No. : 26646

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**AARON C. DEDITCH**  
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**AMENDMENT AFTER A FINAL OFFICE ACTION**

S I R:

In response to the Final Office Action mailed on June 7, 2004 (the three-month response date for which has been extended by two months from September 7, 2004 to November 7, 2004), please reconsider the above-identified application based on the following:

**Amendments to the Claims** are reflected in the listing of the claims which begins on page 2 of this paper.

**Remarks** begin on page 7 of this paper.